
	<h2>SI3805DV-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI3805DV-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 3.3A 6-TSOP</p> <p>Datenblätter:  SI3805DV-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 37519 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3805DV-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CH 20V 3.3A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	37519 pcs Stock
detaillierte Beschreibung	P-Channel 20V 3.3A (Tc) 1.1W (Ta), 1.4W (Tc) Surface
Serie	LITTLE FOOT®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.1W (Ta), 1.4W (Tc)
Typ FET	P-Channel
FET-Merkmal	Schottky Diode (Isolated)
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.3A (Tc)
Rds On (Max) @ Id, Vgs	84 mOhm @ 3A, 10V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	330pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































SI3805DV-T1-E3 ist neu im Original, Suche SI3805DV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3805DV-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI3805DV-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI3803DV T1 03 VISHAY VISHAY SOT-163	 SI3805DV-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 3.3A 6-TSOP	 SI3803DV-T1 VISHAY SI3803DV-T1 VISHAY	 SI3812DV-T1-E3 Vishay / Siliconix MOSFET N-CH 20V 2A 6-TSOP
 SI3801DV T1 01EN SI SI SOT-163	 SI3801DV-T1 VISHAY SI3801DV-T1 VISHAY	 SI3812DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 2A 6-TSOP	 SI3805DV-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 3.3A 6-TSOP

heiße Teile

Mehr

 SI3585CDV-T1-GE3	 SI3585CDV-T1-GE3	 SI3585DV	 SI3585DV-T1	 SI3585DV-T1-E3
 SI3585DV-T1-E3	 SI3585DV-T1-GE3	 SI3585DV-T1-GE3	 SI3586DS-TI-E3	 SI3586DV
 SI3586DV-T1-E3	 SI3586DV-T1-E3	 SI3586DV-T1-GE3	 SI3586DV-T1-GE3	 SI3588DV
 SI3588DV-T1-E3	 SI3588DV-T1-E3	 SI3588DV-T1-GE3	 SI3588DV-T1-GE3	 SI3590DV-T1-GE3
 SI3590DV-T1-GE3	 SI3801DV-T1	 SI3803DV-T1	 SI3805DV-T1	 SI3805DV-T1-E3
 SI3812DV-T1-GE3	 SI3812DV-T1-GE3	 SI3850ADV-T1-E3	 SI3850ADV-T1-E3	 SI3850ADV-T1-GE3
 SI3850ADV-T1-GE3	 SI3850DV-T1	 SI3850DV-T1-E3	 SI3850DV-T1-GE3	 SI3851DV
 SI3851DV-T1	 SI3851DV-T1-E3	 SI3851DV-T1-E3	 SI3851DV-T1-GE3	 SI3853DV-T1-E3
 SI3853DV-T1-E3	 SI3861BDV-T1-GE3	 SI3861BDV-T1-GE3	 SI3861DV-NL	 SI3861DV-T1-E3
 SI3863BDV-T1-GE3	 SI3863DV-T1-E3	 SI3863DV-T1-GE3	 SI3865BDV-T1-E3	 SI3865BDV-T1-E3

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